

NTE74LS75 Integrated Circuit TTL – 4-Bit Bistable Latch

Description:

The NTE74LS75 is a 4-bit bistable latch in a 16-Lead plastic DIP type package that is ideally suited for use as temporary storage for binary information between processing units and input/output or indicator units. Information present at a data (D) input is transferred to the Q output when the enable (C) is high and the Q output will follow the data input as long as the enable remains high. When the enable goes low, the information (that was present at the data input at the time the transition occurred) is retained at the Q output until the enable is permitted to go high.

The NTE74LS75 features complementary Q and \overline{Q} outputs from a 4-bit latch and are completely compatible with all popular TTL families. All inputs are diode-clamped to minimize transmission-line effects and simplify system design.

Absolute Maximum Ratings: (Note 1)

Supply Voltage, V _{CC}	7V
Input Voltage	7V
Operating Temperature Range, T _A	\dots 0°C to +70°C
Storage Temperature Range, T _{stg}	-65°C to +150°C

Note 1. Voltage values are with respect to network ground terminal.

Recommended Operating Conditions:

Parameter	Symbol	Min	Тур	Max	Unit
Supply Voltage	V _{CC}	4.75	5.0	5.25	V
High-Level Output Current	Іон	_	_	-400	μΑ
Low-Level Output Current	I _{OL}	_	-	8	mA
Width of Enabling Pulse	t _w	20	-	-	ns
Setup Time	t _{su}	20	_	-	ns
Hold Time	t _h	5	_	-	ns
Operating Temperature Range	T _A	0	_	+70	°C

Electrical Characteristics: (Note 2, Note 3)

Parameter	Symbol	Test Conditions		Min	Тур	Max	Unit
High Level Input Voltage	V _{IH}			2	-	_	V
Low Level Input Voltage	V _{IL}			_	_	0.8	V
Input Clamp Voltage	V _{IK}	$V_{CC} = MIN, I_I = -18mA$		_	_	-1.5	V
High Level Output Voltage	V _{OH}	$V_{CC} = MIN, V_{IH} = 2V, V_{IL} = MA$	AX, I _{OH} = -400μA	2.7	3.5		V
Low Level Output Voltage	V _{OL}	$V_{CC} = MIN, V_{IH} = 2V, I_{OL} = 4mA$	_	0.25	0.4	V	
		$V_{IL} = MAX$	$V_{IL} = MAX$ $I_{OL} = 8mA$	_	0.35	0.5	V
Input Current D Input	II	V _{CC} = MAX, V _I = 7V	•	_	_	0.1	mA
C Input	1			_	-	0.4	mA
High Level Input Current D Input	I _{IH}	$V_{CC} = MAX, V_I = 2.7V$		_	_	20	μΑ
C Input				_	-	80	μΑ
Low Level Input Current D Input	I _{IL}	$V_{CC} = MAX, V_I = 0.4V$		_	_	-0.4	mA
C Input	1			_	-	-1.6	mA
Short-Circuit Output Current	Ios	V _{CC} = MAX, Note 4		-20	-	-100	mA
Supply Current	I _{CC}	V _{CC} = MAX, Note 5		_	6.3	12	mA

- Note 2. .For conditions shown as MIN or MAX, use the appropriate value specified under "Recommended Operation Conditions".
- Note 3. All typical values are at $V_{CC} = 5V$, $T_A = +25$ °C.
- Note 4. Not more than one output should be shorted at a time, and duration of the short-circuit should not exceed one second.
- Note 5. I_{CC} is measured with all outputs open and all inputs grounded.

<u>Switching Characteristics</u>: $(V_{CC} = 5V, T_A = +25^{\circ}C \text{ unless otherwise specified})$

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Propagation Delay Time	t _{PLH}	$R_L = 2k\Omega$, $C_L = 15pF$	-	15	27	ns
(From D input to Q Output)	t _{PHL}	1	_	9	17	ns
Propagation Delay Time (From D input to Q Output)	t _{PLH}	1	_	12	20	ns
(From D input to Q Output)	t _{PHL}	1	_	7	15	ns
Propagation Delay Time	t _{PLH}	1	_	15	27	ns
(From C input to Q Output)	t _{PHL}	1	_	14	25	ns
Propagation Delay Time	t _{PLH}	1	_	16	30	ns
(From C input to Q Output)	t _{PHL}		-	7	15	ns

Function Tables:

Inp	uts	Outputs	
D	С	Q	Q
L	Н	L	Н
Н	Н	Н	L
Х	L	Q_0	\overline{Q}_0

H = HIGH Level, L = LOW Level, X = Irrelevant

Q₀ = The level of Q before the high-to-low transition of G

